

Vishay Siliconix

RoHS

COMPLIANT

Precision Monolithic Quad SPST CMOS Analog Switches

DESCRIPTION

The DG411HS series of monolithic quad analog switches was designed to provide high speed, low error switching of precision analog signals. Combining low power (0.35 μ W) with high speed (t_{ON}: 68 ns), the DG411HS family is ideally suited for portable and battery powered industrial and military applications.

To achieve high-voltage ratings and superior switching performance, the DG411HS series was built on Vishay Siliconix's high voltage silicon gate process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks input voltages up to the supply levels when off.

The DG411HS and DG412HS respond to opposite control logic as shown in the Truth Table. The DG413HS has two normally open and two normally closed switches.

FEATURES

- 44 V supply max. rating
- ± 15 V analog signal range
- On-resistance R_{DS(on)}: 25 Ω
- Fast switching t_{ON}: 68 ns
- Ultra low power P_D: 0.35 μW
- TTL, CMOS compatible
- Single supply capability

BENEFITS

- · Widest dynamic range
- Low signal rrrors and distortion
- Break-before-make switching action
- Simple interfacing

APPLICATIONS

- · Precision automatic test equipment
- Precision data acquisition
- Communication systems
- Battery powered systems
- Computer peripherals

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG411HS DG411HS DG411HS QFN16 Dual-In-Line and SOIC I CC IN₁ IN₂ D₂ D₁ D₁ IN₁ NC IN₂ D₂ IN₁ IN_2 Key 16 15 14 13 D_2 D₁ 2 S S_1 4 S_2 S₁ 3 S_2 v-V-V+ 13 V-2 11 V+ NC GND V_{L} 5 GND 3 V_{L} 10 GND S_3 S_4 6 S4 S₃ S4 D_4 10 D_3 IN_4 8 9 IN₃ 5 6 D_4 IN_4 IN_3 D₃ D_4 IN₄ NC IN_3 D₃ Top View Top View Top View

TRUTH TABLE						
Logic	Logic DG411HS DG412HS					
0	ON	OFF				
1	OFF	ON				

* Pb containing terminations are not RoHS compliant, exemptions may apply

 S_2

V+

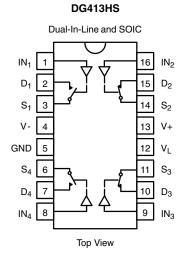
NC

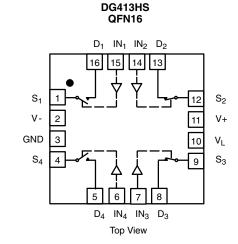
VL

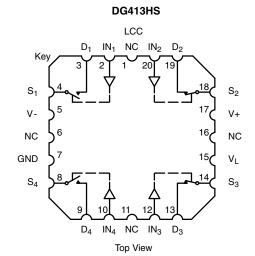
 S_3

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FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION







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TRUTH TABLE							
Logic SW ₁ , SW ₄ SW ₂ , SW ₃							
0	OFF	ON					
1	ON	OFF					

ORDERING INFORMA				
Temp. Range	Package	Part Number		
DG411HS, DG412HS				
	16-Pin Plastic DIP	DG411HSDJ DG411HSDJ-E3		
		DG412HSDJ DG412HSDJ-E3		
- 40 °C to 85 °C		DG411HSDY DG411HSDY-E3 DG411HSDY-T1 DG411HSDY-T1-E3		
	16-Pin Narrow SOIC	DG412HSDY DG412HSDY-E3 DG412HSDY-T1 DG412HSDY-T1-E3		
	16-Pin QFN 4 x 4 mm	DG411HSDN-T1-E4 DG412HSDN-T1-E4		
DG413HS				
	16-Pin Plastic DIP	DG413HSDJ DG413HSDJ-E3		
- 40 °C to 85 °C	16-Pin Narrow SOIC	DG413HSDY DG413HSDY-E3 DG413HSDY-T1 DG413HSDY-T1-E3		
F	16-Pin QFN 4 x 4 mm	DG413HSDN-T1-E4		

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ABSOLUTE MAXIMUM RA	TINGS			
Parameter		Limit	Unit	
V+ to V-		44		
GND to V-		25		
VL		(GND - 0.3) to (V+) + 0.3	V	
Digital Inputs ^a , V _S , V _D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first		
Continuous Current (Any terminal)		30	mA	
Peak Current, S or D (Pulsed 1 ms, 10 S	% duty cycle)	100		
Storage Temperature	(AK, AZ Suffix)	- 65 to 150	°C	
Storage temperature	(DJ, DY, DN Suffix)	- 65 to 125	C	
	16-Pin Plastic DIP ^c	470		
	16-Pin Narrow SOIC ^d	600		
Power Dissipation (Package) ^b	16-Pin CerDIP ^e	900	mW	
	LCC-20 ^e	900		
	16-Pin (4 x 4 mm) QFN ^f	1880		

Notes:

- a. Signals on S_X , D_X , or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.

c. Derate 6 mW/°C above 25 °C.

d. Derate 7.6 mW/°C above 75 °C.

e. Derate 12 mW/°C above 75 °C.

f. Derate 23.5 mW/°C above 70 °C.

SPECIFICATIONS	3								
		Test Conditions Unless Specified			A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C		
Parameter	Symbol	V+ = 15 V, V- = - 15 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f	Temp. ^b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Uni
Analog Switch					•	•		•	
Analog Signal Range ^e	V _{ANALOG}		Full		- 15	15	- 15	15	V
Drain-Source On-Resistance	R _{DS(on)}	V+ = 13.5 V, V- = - 13.5 V I _S = - 10 mA, V _D = ± 8.5 V	Room Full	25		35 45		35 45	Ω
Switch Off Leakage Current	I _{S(off)}	$V_{\rm p} = \pm 15.5 \text{ mA}, V_{\rm s} = \pm 15.5 \text{ V}$	Room Full	± 0.1	- 0.25 - 20	0.25 20	- 0.25 - 5	0.25 5	nA
	I _{D(off)}		Room Full	± 0.1	- 0.25 - 20	0.25 20	- 0.25 - 5	0.25 5	
Channel On Leakage Current	I _{D(on)}	V+ = 16.5 V, V- = - 16.5 V V _D = V _S = ± 15.5 V	Room Full	± 0.1	- 0.4 - 40	0.4 40	- 0.4 - 10	0.4 10	
Digital Control			<u> </u>		•				
Input Current, VIN Low	۱ _{IL}	V _{IN} under test = 0.8 V	Full	0.005	- 0.5	0.5	- 0.5	0.5	
Input Current, V _{IN} High	I _{IH}	V _{IN} under test = 2.4 V	Full	0.005	- 0.5	0.5	- 0.5	0.5	μA
Input Capacitance ^e	C _{IN}	f = 1 MHz	Room	5					pF
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF	Room Full	68		105 127		105 116	
Turn-Off Time	t _{OFF}	$V_{\rm S} = \pm 10$ V, see figure 2	Room Full	42		80 94		80 90	ns
Break-Before-Make Time Delay	t _D	DG413HS only, V _S = 10 V R _L = 300 Ω, C _L = 35 pF	Room	20					
Charge Injection ^e	Q	$V_{q} = 0 V, R_{q} = 0 \Omega, C_{L} = 10 nF$	Room	22					pC

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SPECIFICATIONS ^a										
		Test Conditions Unless Specified			A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C			
Parameter	Symbol	V+ = 15 V, V- = - 15 V V _L = 5 V, V _{IN} = 2.4 V, 0.8 V ^f	Temp. ^b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Unit	
Dynamic Characteristics (Cont	ťd)									
Off Isolation ^e	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$	Room	- 91					dB	
Channel-to-Channel Crosstalk ^e	X _{TALK}	f = 1 MHz	Room	- 88					uБ	
Source Off Capacitance ^e	C _{S(off)}		Room	12						
Drain Off Capacitance ^e	C _{D(off)}	f = 1 MHz	Room	12					pF	
Channel On Capacitance ^e	C _{D(on)}		Room	30						
Power Supplies										
Positive Supply Current	l+		Room Full	0.0001		1 5		1 5		
Nagativa Supply Current	-		Room	- 0.0001	- 1		- 1			
Negative Supply Current	1-	V+ = 16.5 V, V- = - 16.5 V	Full		- 5		- 5		μA	
Logic Supply Current	١ _L	V _{IN} = 0 or 5 V	Room Full	0.0001		1 5		1 5	μΛ	
Ground Current	I _{GND}		Room Full	- 0.0001	- 1 - 5		- 1 - 5			

SPECIFICATIONS ^a (for Unipolar Supplies)									
		Test Conditions Unless Specified			A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C		
Parameter	Symbol	$V_{+} = 12 V, V_{-} = 0 V$ $V_{L} = 5 V, V_{IN} = 2.4 V, 0.8 V^{f}$	Temp. ^b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Unit
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full			12		12	V
Drain-Source On-Resistance	R _{DS(on)}	V+ = 10.8 V, I _S = - 10 mA V _D = 3 V, 8 V	Room Full	49		80 100		80 100	Ω
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF	Room Hot	95		140 180		140 160	
Turn-Off Time	t _{OFF}	$V_{S} = 8 V$, see figure 2	Room Hot	36		70 79		70 74	ns
Break-Before-Make Time Delay	t _D	DG413HS only, $V_S = 8 V$ R _L = 300 Ω, C _L = 35 pF	Room	60					
Charge Injection	Q	$V_{g} = 6 V, R_{g} = 0 \Omega, C_{L} = 1 nF$	Room	60					рС
Power Supplies			•		•	•		•	
Positive Supply Current	l+		Room Hot	0.0001		1 5		1 5	
Negative Supply Current	-	V+ = 13.2 V, V _{IN} = 0 or 5 V	Room Hot	- 0.0001	- 1 - 5		- 1 - 5		
Logic Supply Current	۱ _L		Room Hot	0.0001		1 5		1 5	μA
Ground Current	I _{GND}		Room Hot	- 0.0001	- 1 - 5		- 1 - 5		

Notes:

a. Refer to PROCESS OPTION FLOWCHART.

b. Room = 25 $^{\circ}$ C, Full = as determined by the operating temperature suffix.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

e. Guaranteed by design, not subject to production test.

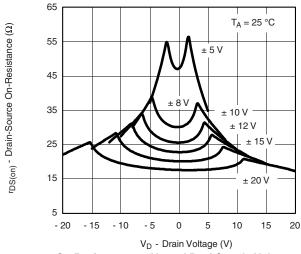
f. V_{IN} = input voltage to perform proper function.

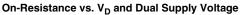
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

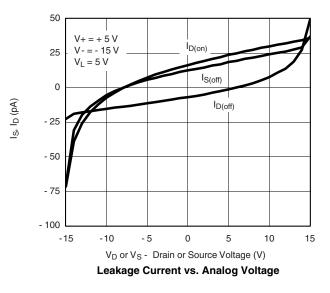


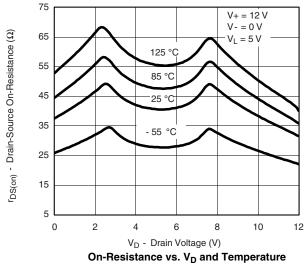
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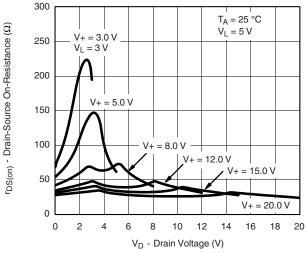
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



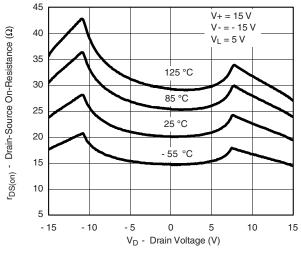




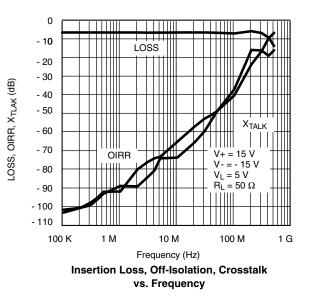




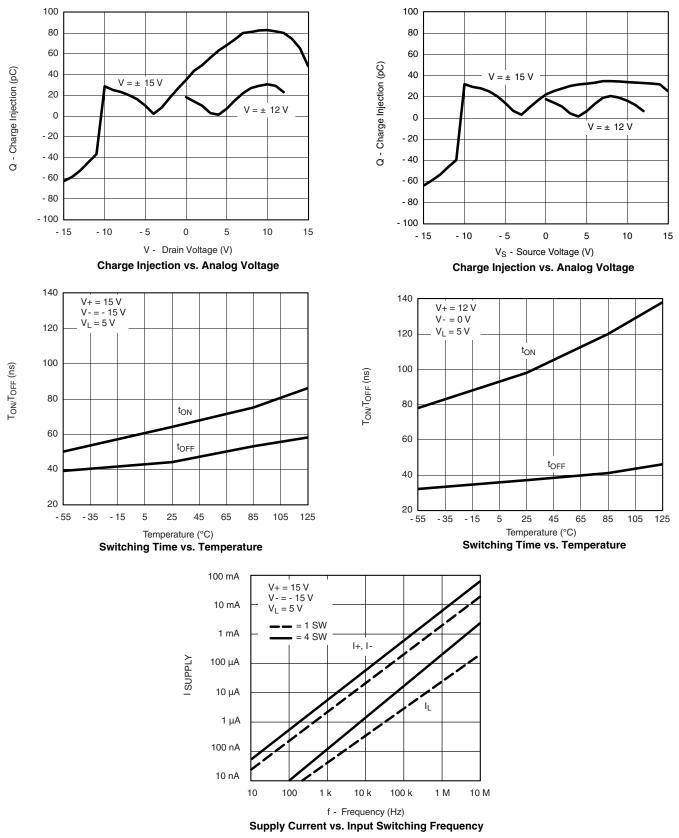
On-Resistance vs. V_D and Unipolar Supply Voltage



On-Resistance vs. V_D and Temperature



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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

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SCHEMATIC DIAGRAM (Typical Channel)

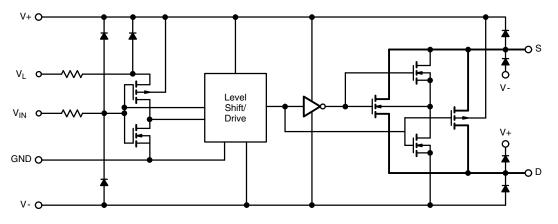
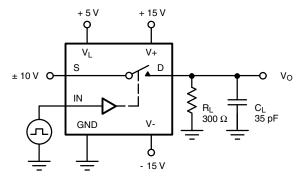


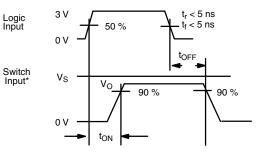
Figure 1.

TEST CIRCUITS



 C_{L} (includes fixture and stray capacitance)

 $V_{O} = V_{S} \qquad \frac{R_{L}}{R_{L} + r_{DS(on)}}$



Note: Logic input waveform is inverted for switches that have the opposite logic sense control



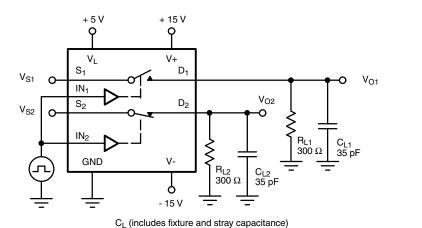
Logic Input

Switch

Output

Switch

Output



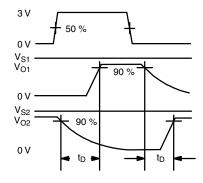


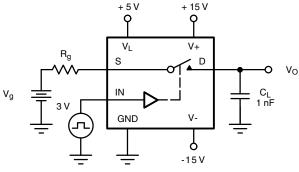
Figure 3. Break-Before-Make (DG413HS)

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TEST CIRCUITS



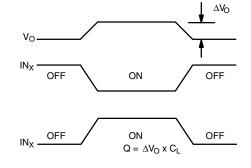


Figure 4. Charge Injection

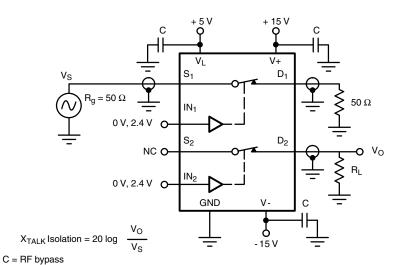
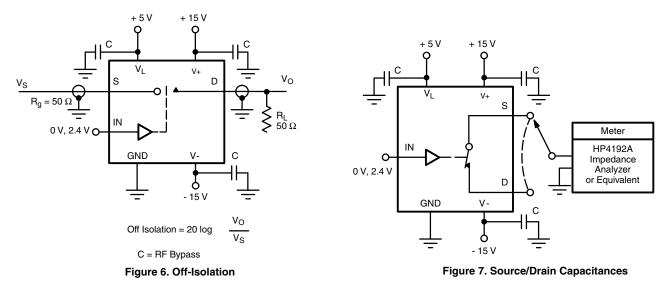


Figure 5. Crosstalk



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